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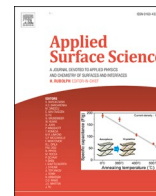
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## Full Length Article

Stretchable strain sensor based on HfSe<sub>2</sub>/LIG composite with high sensitivity and good linearity within a wide range

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## ABSTRACT

Flexible strain sensors based on nanomaterials have sparked a lot of interest in the field of wearable smart electronics. Laser induced graphene (LIG) based sensors in particular stand out due to their straightforward fabrication procedure, three-dimensional porous structures, and exceptional electromechanical capabilities. Recent studies have focused on LIG composites, however, it is still difficult to achieve great sensitivity and excellent linearity in a wide linear working range. Herein, a strain sensor with high sensitivity and good linearity is prepared in this work, which was realized by carbonizing the polyimide film coated with HfSe<sub>2</sub> to obtain three-dimensional porous graphene nanosheets decorated with HfSe<sub>2</sub> (HfSe<sub>2</sub>/LIG). After being transferred to the flexible substrate of Ecoflex, it exhibits high stretchability, hydrophobicity and robustness, and obtains excellent electromechanical properties. The HfSe<sub>2</sub>/LIG strain sensor demonstrated high sensitivity (gauge factor, GF  $\approx$  46), a low detection limit (0.02%), good linearity ( $R^2 = 0.99$ ) in a large working range (up to 30%), and a quick response time (0.20 s). Additionally, it exhibits good stability and consistent behavior across a large number of strain/release test cycles (>3000 cycles). With these benefits, the sensor can be used to monitor various limb movements (including finger, wrist and neck movements) and minute artery activity, and can generate reliable signals. Therefore, the HfSe<sub>2</sub>/LIG-based sensor has enormous potential for use in wearable intelligent electronics and movement monitoring.

## 1. Introduction

Wearable strain sensors have several potential applications in healthcare, [1–4] human-interactive systems, [5,6] and electronic skin [7,8] thanks to their flexibility, high sensitivity, and mechanical robustness. Despite the extensive study in this subject over decades, it remains difficult to build flexible strain sensors with effective and scalable manufacturing methods to achieve ideal stimulation conversion capability and stable signal output over a long working duration. Numerous options have been looked into as the active materials of strain sensors, including metal nanowires [9,10], MXene [11], conductive polymer [12,13], and carbon materials [14,15] (carbon black [16], carbon nanotubes (CNT) [17,18] and graphene [19,20]). Due to their outstanding mechanical and electrical properties, graphene-based materials serve as a typical category of two-dimensional (2D) carbon-based

materials and are particularly well suited for strain sensor applications. Han et al. [21] used chemical vapor deposition to produce the graphene mesh networks (gauge factor, GF = 2.55 at 70% strain). Stretchable and sensitive strain sensors were created by He et al. [22] using porous polydimethylsiloxane (PDMS) hybrids with CNTs and graphene. Although these sensors based on graphene have excellent sensitivity, graphene materials nevertheless have to deal with difficult preparation procedures and ductility.

The invention of laser-induced graphene (LIG) has created a new method for producing high-performance sensors that is simple, efficient and low-cost manufacturing [23–26]. By directly irradiating carbonaceous precursors, LIG is quickly created and has a porous three-dimensional structure by nature. In sensors, LIG and its variants have found widespread use [24,27,28]. Liu et al. [29] produced porous graphene strain sensors directly on PI fabrics. Kulyk et al. [30] prepared LIG

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flexible sensor on filter paper. These LIG strain sensors fabricated on pristine substrates have certain flexibility and stretchability, however, due to the limited stretchability of the substrate and the weak adhesion of LIG to the substrate, its stretchability range is narrow and its stability is weak. The application potential of LIG is limited by its robustness on substrates. In order to further improve the stability and stretching range of LIG, Tour team [31] developed LIG composites (LIGCs) that are engineered on various substrate by simple infiltration method. Wu et al. [32] fabricated a piezoresistive strain sensor by combining LIG with an elastic substrate (PDMS or Ecoflex), exhibiting a high GF of 37 and a stretch range of 70%. Dallinger et al. [33] prepared highly stretchable (100% strain) and sensitive ( $GF = 40$ ) strain sensors based on LIG/Polyurethane. These methods improve adhesion and increase the penetration of elastic materials into the carbon network. Therefore, the stretching range of the fabricated strain sensor is widened, but the sensitivity and linearity in a wide range still need to be improved.

Recent research has centered on LIG composites based rare metals. An constructed strain sensor that is loaded with Pt/LIG was created by Liu et al. [34] and has an ultra-high sensitivity ( $GF_{\max} = 489.3$ ) and a large strain range of up to 20%. A novel strain sensor with layered cracks built of Au/graphene composite film was proposed by Gong et al. [35], and it demonstrated great sensitivity ( $GF \approx 153$ ) and favorable linearity ( $R^2 \approx 0.9975$ ) in the broad working range (0–20%). Ag/LIG strain sensors with great sensitivity ( $GF = 223.6$ ) and a wide operating range (70%–100%) were created by Xie et al. [36] By adding rare metals to LIG, the electromechanical characteristics are enhanced, but the cost is also raised.

Due to their layered structures and tunable characteristics, transition metal dichalcogenides (TMDs) have garnered a lot of attention in the past ten years as potential materials for flexible electronics [37,38]. Especially, molybdenum disulfide ( $MoS_2$ ) is one of the candidates in high-performance flexible strain sensors owing to its excellent mechanical properties [39]. Park's team [40] proposed highly sensitive strain sensors ( $GF \approx 1242$ ) based on  $MoS_2$ -decorated LIG. Its electromechanical properties are improved by taking advantage of the high mobility of graphene and the structural rigidity of  $MoS_2$ . In addition to  $MoS_2$ , hafnium diselenide ( $HfSe_2$ ) is a particularly interesting member, because it shows a moderate band gap and outstanding mechanical properties. The Young's modulus, fracture strength, and maximal strain of  $HfSe_2$  were recently measured to be  $\sim 39.3 \pm 8.9$  GPa,  $4.5 \pm 1.4$  GPa, and 14.0–20.9%, respectively, [41] which far exceeds the stretchability of other 2D materials including  $MoS_2$  [42]. And hafnium oxide ( $HfO_2$ ) prepared by laser irradiation of the  $HfSe_2$  surface exhibits a higher Yang's modulus ( $182.6 \pm 54.3$  GPa) [41].  $HfSe_2$  is appealing in strain sensors due to its exceptional elasticity, excellent electrical and photoelectric properties. However, because there has been little research on  $HfSe_2$  flexible strain sensors, this work investigates a stretchable strain sensor based on  $HfSe_2$ /LIG.

Herein, we proposed a simple method for fabricating  $HfSe_2$  embedded LIG porous composite ( $HfSe_2$ /LIG) for use in wearable strain sensors. Three-dimensional porous graphene with  $HfSe_2$  decorations was created by irradiating a multilayer  $HfSe_2$  coating on a commercial PI film with a  $CO_2$  infrared laser, which produces superior electromechanical properties. According to the experimental results, the  $HfSe_2$ /LIG composite material on Ecoflex substrate exhibits high sensitivity ( $GF \approx 46$ ) and good linearity ( $R^2 = 0.99$ ) over a wide tensile range (0–30%). When under strain conditions of 30–50%,  $GF_{\max} \approx 150$ . And it has high tensile durability (>3000 cycles). Further evidence of their broad potential for use in wearable electronics comes from the fact that reliable signals can be picked up from a variety of human body motion-monitoring tests (such as those performed on the fingers, wrists, and neck) as well as subtle pulse perception.

## 2. Experimental section

### 2.1. The production process of $HfSe_2$ solution

$HfSe_2$  solution was made by mixing 5 ml of ethanol (anhydrous, 99.8%, Sigma Aldrich) solvent with 10 mg of hafnium diselenide powder ( $HfSe_2$ , purchased from Shenzhen Six Carbon Technology). The obtained mixture was immersed in an SBL-15DT benchtop ultrasonic bath (400 W) for 12 h at a frequency of 40 kHz and 100% power sonication. During sonication, the bath temperature was kept below 30 °C by a water-cooled circulating pump. The  $HfSe_2$  ethanol dispersion was obtained, the upper layer was taken, spray-coated on the surface of a 100  $\mu$ m polyimide film (PI film), and the solvent was then evaporated in a blast drying oven at 80 °C for 30 min.

### 2.2. Fabrication of $HfSe_2$ /LIG strain sensor

The  $HfSe_2$ -coated PI film was irradiated with a  $CO_2$  infrared laser. A 10.6  $\mu$ m  $CO_2$  laser with a maximum power of 40 W was used in this study. The final device was produced using the laser parameters that have been optimized, which have a power of 7% and a speed of 80 mm/min in ambient conditions.

Ecoflex 00–20 (Smooth-On) was used as the  $HfSe_2$ /LIG strain sensor substrate in this study, and its parts A and B were mixed in a weight ratio of 1:1 before being degassed and drop-cast onto the laser-patterned  $HfSe_2$ /LIG film (thickness about 0.5 mm). The PI film was then peeled off to realize the transfer of  $HfSe_2$ /LIG to the surface of the Ecoflex flexible substrate after the Ecoflex film had been cured at 80 °C for 4 h. Then, by joining  $HfSe_2$ /LIG patterns with copper wires, electrical contact was created with the aid of silver paste. Finally, Ecoflex suspension was used for the final encapsulation (thickness about 0.5 mm), creating a completely flexible strain sensor.

### 2.3. Materials characterizations and electromechanical measurement

The surface morphology of the  $HfSe_2$ /LIG network was examined using scanning electron microscope (SEM, Gemini 300, Zeiss) images for material characterization. The same instrument was also used to conduct energy dispersive X-ray spectroscopy (EDS) for elemental analysis. By using LabRAM HR Evolution (HORIBA) and a 532 nm laser to excite it, Raman spectrum was obtained. X-ray photoelectron spectroscopy (XPS) spectra of  $HfSe_2$ /LIG were also measured. The XPS analyses were carried out on a PHI 5000 VersaProbe III spectrometer using monochromatic Al( $\alpha$ ) X-ray source ( $h\nu = 1486.6$  eV). The analyzer pass energy is selected as 280.0 eV and step size of 1.0 eV. High resolution analyses were carried out with same X-ray settings and analysis area, while analyzer pass energy is selected at 69.0 eV and step size of 0.125 eV. Spectra have been charge corrected to the main line of the C 1 s spectrum (adventitious carbon) and set to BE of 284.8 eV. The acquired data were analyzed using PHI MultiPak software. During element curve fitting, a “Shirley” background subtraction method is used and fitting curve line-shape had chosen to use the “Gaussian-Lorentzian” function. The lattice fringes and spacing of LIG and  $HfSe_2$  were characterized using a field emission gun transmission electron microscope (TEM, Talos F200s) with energy dispersive spectrometer (EDS, SUPER X).

The static testing apparatus (Wance Instrumente) was used to apply longitudinal strain to the  $HfSe_2$ /LIG strain sensor during electromechanical testing. A multichannel data acquisition system (DAQ6510, Keithley) was utilized to record the resistance signal in real time during the stretching and releasing process. And a digital source meter (2450, Keithley) was applied to measure the I-V curve.

### 3. Results and discussion

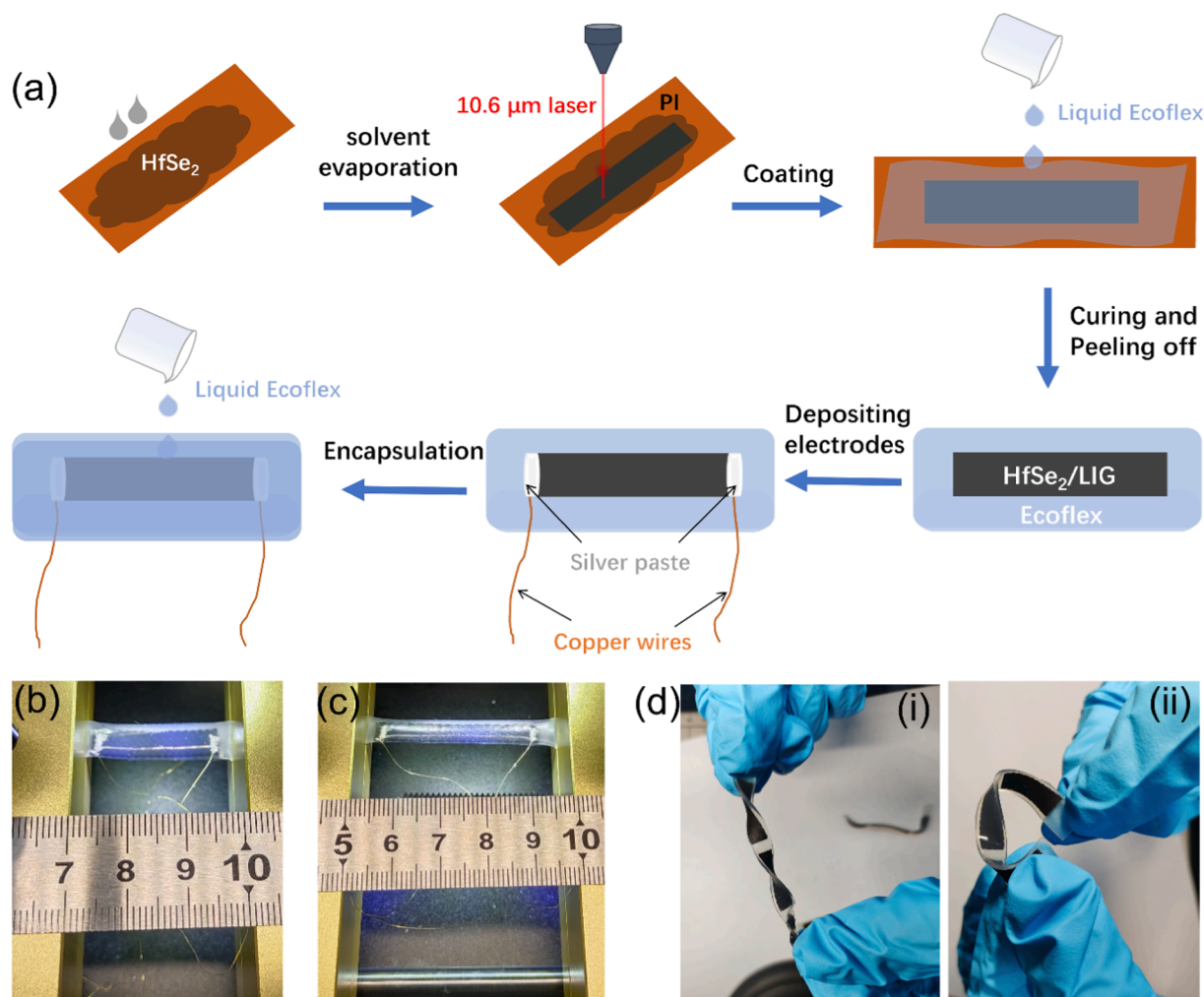
#### 3.1. Fabrication and characterization of $\text{HfSe}_2/\text{LIG}$ strain sensor

Fig. 1a illustrates the fabrication process of the  $\text{HfSe}_2$ -decorated LIG ( $\text{HfSe}_2/\text{LIG}$ ) strain sensor. Firstly,  $\text{HfSe}_2$  dispersion was sprayed on PI film by a spray gun, which can reduce the surface tension of dispersion and make  $\text{HfSe}_2$  cover the PI surface more evenly. Secondly, the film was treated with a 10.6  $\mu\text{m}$   $\text{CO}_2$  laser to obtain  $\text{HfSe}_2/\text{LIG}$ . To increase the ductility and mechanical robustness,  $\text{HfSe}_2/\text{LIG}$  was transferred to the surface of the Ecoflex flexible substrate by infiltration method, and the Ecoflex- $\text{HfSe}_2/\text{LIG}$  composite film was obtained. Video\_S1 (Supporting Information) shows the surface robustness after transfer. Next, the copper wire was connected to the  $\text{HfSe}_2/\text{LIG}$  pattern through silver paste to make electrical contact. Finally, Ecoflex suspension was adopted in the encapsulation, thus forming a complete flexible strain sensor with a size of 25 mm  $\times$  5 mm, as shown in Fig. 1b. The sensor has good flexibility and stretchability. Fig. 1c shows the sensor after stretching at about 100% strain, and Fig. 1d shows the bending characteristics of the sensor.

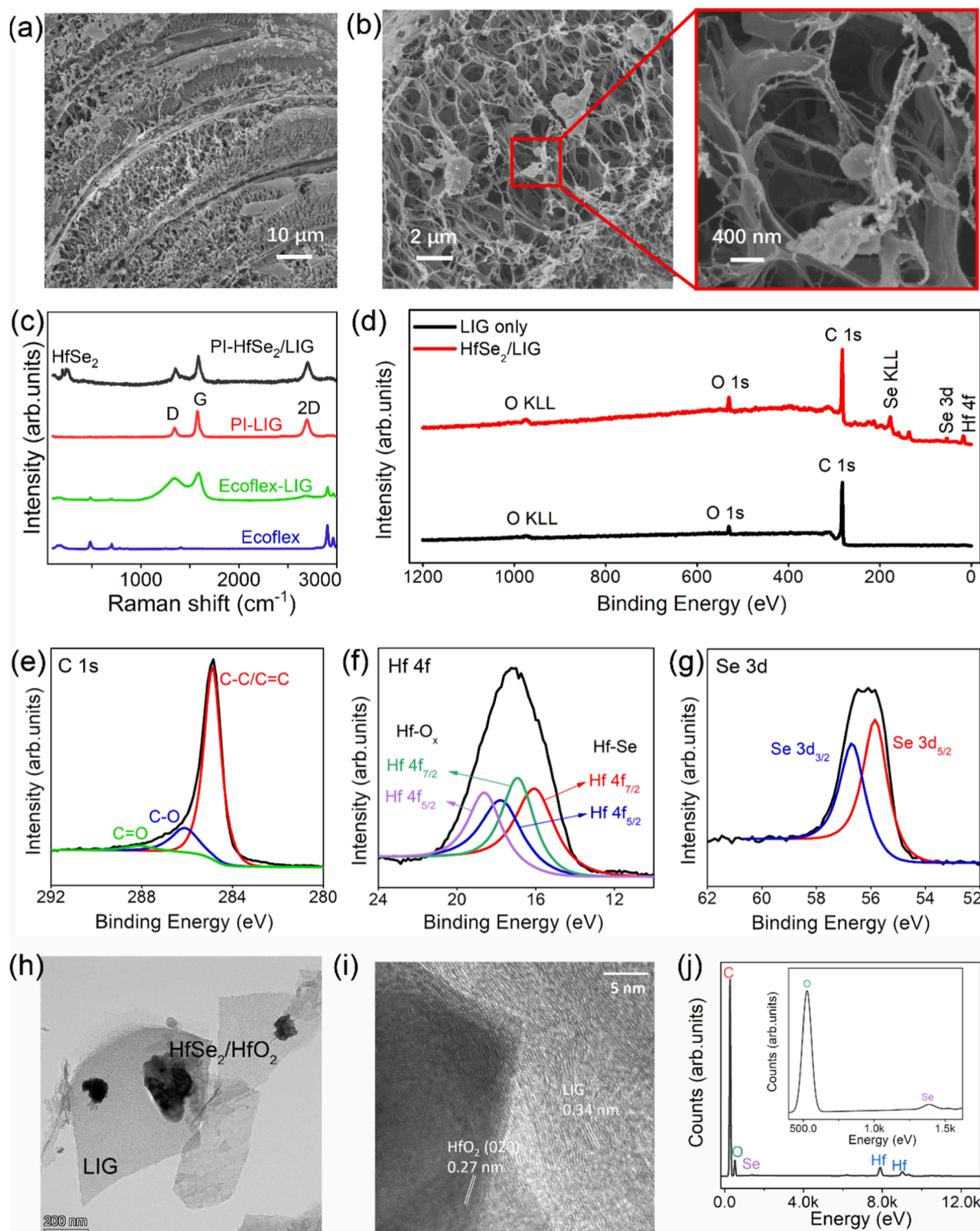
The SEM image from Fig. 2a depicts the morphology and micro-structure of  $\text{HfSe}_2/\text{LIG}$  on PI substrate (PI- $\text{HfSe}_2/\text{LIG}$ ). The results indicate that  $\text{HfSe}_2/\text{LIG}$  is a three-dimensional network structure, which is consistent with the results in the literature [23,34,40]. And  $\text{HfSe}_2$  is dispersed on the surface of LIG, which is shown in Fig. 2b, and the

elemental mapping of  $\text{HfSe}_2/\text{LIG}$  is shown in Fig. S1a, which reveals that the composites include C, Hf, Se and O atoms. After that, the surface is poured with Ecoflex liquid, and its fluidity will automatically fill into the three-dimensional network structure, which is conducive to the transfer of  $\text{HfSe}_2/\text{LIG}$ . The morphology of the transferred surface (Ecoflex- $\text{HfSe}_2/\text{LIG}$ ) is shown in Fig. S2b. And the cross-section SEM images (Fig. S2c-d) of  $\text{HfSe}_2/\text{LIG}$  on PI and Ecoflex substrate both show the thickness of  $\text{HfSe}_2/\text{LIG}$  is about 50  $\mu\text{m}$ . The contact angle of  $\text{HfSe}_2/\text{LIG}$  on PI and Ecoflex substrate was also tested, respectively, as shown in Fig. S2e-f. The results indicate that  $\text{HfSe}_2/\text{LIG}$  surface changed from hydrophilic (contact angle of 52.68°) to hydrophobic (contact angle of 118.78°) after transferring to the Ecoflex substrate, thus improving the robustness and environmental stability of the  $\text{HfSe}_2/\text{LIG}$  strain sensor.

Raman spectra were measured to further characterize the chemical structure of  $\text{HfSe}_2/\text{LIG}$ . Fig. 2c depicts the Raman spectrum of PI-LIG, Ecoflex-LIG and PI- $\text{HfSe}_2/\text{LIG}$  for analyzing their differences. Three typical characteristic peaks of LIG at  $\sim 1350$ , 1585 and 2700  $\text{cm}^{-1}$  were identified in the above materials, and these peaks are consistent with the Raman spectra of typical LIG obtained by laser irradiation of PI films previously reported [23,34]. The above three typical characteristic peaks correspond to D peak (indicating that  $\text{sp}^2$  carbon bond is defective or bent), G peak (showing the first-order scattering vibration of  $\text{sp}^2$  hybrid carbon atoms, suggesting graphitization), and 2D peak (related to the boundary phonons of the second-order region and determined by the number of graphene stacks), respectively [23,43]. Among them, the



**Fig. 1.** Preparation process and device pictures of stretchable strain sensor based on  $\text{HfSe}_2/\text{LIG}$ . (a) Fabrication schematic diagram of resistive flexible strain sensor based on  $\text{HfSe}_2/\text{LIG}$ . (b)-(c) Photographs show the final strain sensor with a size of 25 mm  $\times$  5 mm at 0% and 100% strain, respectively. (d) Photographs show the bending characteristics of the sensor.



**Fig. 2.** Characterization and analysis of HfSe<sub>2</sub>/LIG composites. (a)–(b) Morphology and microstructure of HfSe<sub>2</sub>/LIG on PI substrate. (c) Raman spectrum of PI-LIG, Ecoflex-LIG, and PI-HfSe<sub>2</sub>/LIG. (d) The full XPS spectra of HfSe<sub>2</sub>/LIG composites and LIG-only. (e) The XPS spectrum of C 1s, indicating that the C–C peak of LIG in the HfSe<sub>2</sub>/LIG composite is the main part. (f) The XPS spectrum of Hf 4f. (g) The XPS spectrum of Se 3d. (h) Low-magnification TEM image of HfSe<sub>2</sub>/LIG. (i) HRTEM image of HfSe<sub>2</sub>/LIG. (j) EDS spectrum of the HfSe<sub>2</sub>/LIG.

Raman spectrum of Ecoflex-LIG shows that the FWHM (Full width at half maximum) of G and D peaks increases, and the intensity of 2D peaks decreases. This is because after transferring, the graphite at the bottom turns to the surface [31,44]. In magnified Raman spectra of PI-HfSe<sub>2</sub>/LIG (Fig. S1b), HfSe<sub>2</sub>-related peaks at 199 cm<sup>-1</sup> were also observed at

low wavenumbers, which is the A<sub>1g</sub> mode and arises from the out-of-plane vibration of Se atoms [45–47]. The other characteristic peaks located at 237 cm<sup>-1</sup> and 257 cm<sup>-1</sup> were also identified, which are derived from selenium (Se) [48]. This is because the laser partially oxidizes the top layers of HfSe<sub>2</sub>, forming HfSe<sub>x</sub>O<sub>y</sub> and precipitating Se [45].

The chemical composition and bonding type of  $\text{HfSe}_2/\text{LIG}$  composites were researched by X-ray photoelectron spectroscopy (XPS). The full XPS spectrum of LIG and  $\text{HfSe}_2/\text{LIG}$  are both shown in Fig. 2d, which further confirms that the elemental composition of  $\text{HfSe}_2/\text{LIG}$  is C, O, Hf and Se atoms, and their chemical states. Furthermore, high-resolution XPS spectrum of the C 1s region (Fig. 2e) shows that the C-C peak is centered at 284.6 eV, which is distinctive of the graphene structure [49]. Fig. 2f shows the Hf-Se bonding ( $\text{Hf } 4f_{5/2}$  and  $4f_{7/2}$ ) peaks of  $\text{HfSe}_2/\text{LIG}$  samples located at 17.87 and 16.12 eV, respectively. And other two Hf peaks are located at 18.60 and 16.87 eV, corresponding to the Hf-O bonds of air-exposed  $\text{HfSe}_2$  [45,50]. When fitting the Hf 4f peak, the constraints of the features settings such as FWHM, spin orbit splitting, and relative intensity are shown in Supporting information. And we observed Se  $3d_{3/2}$  (56.72 eV) and Se  $3d_{5/2}$  (55.85 eV) for Se-Se bonding, [50,51] as shown in Fig. 2g. In Fig. 2h, the TEM image of  $\text{HfSe}_2/\text{LIG}$  confirms that  $\text{HfSe}_2$  nanoparticles are uniformly modified on several layers of LIG, where 0.34 nm lattice spacing is allocated to the (002) plane of graphene, and 0.27 nm lattice spacing is allocated to the (020) plane of  $\text{HfO}_2$  nanoparticles generated after  $\text{HfSe}_2$  surface oxidation (Fig. 2i). [23] In Fig. 2j, the EDS spectra of C, O, Hf, and Se elements indicate the presence of  $\text{HfSe}_2$  nanoparticles on LIG. However, due to the high temperature generated during laser manufacturing, a large amount of surface oxidation occurred, resulting in the generation of  $\text{HfO}_2$ .

Therefore, the above results show that the surface layer of  $\text{HfSe}_2$  can be partially oxidized by laser irradiation.

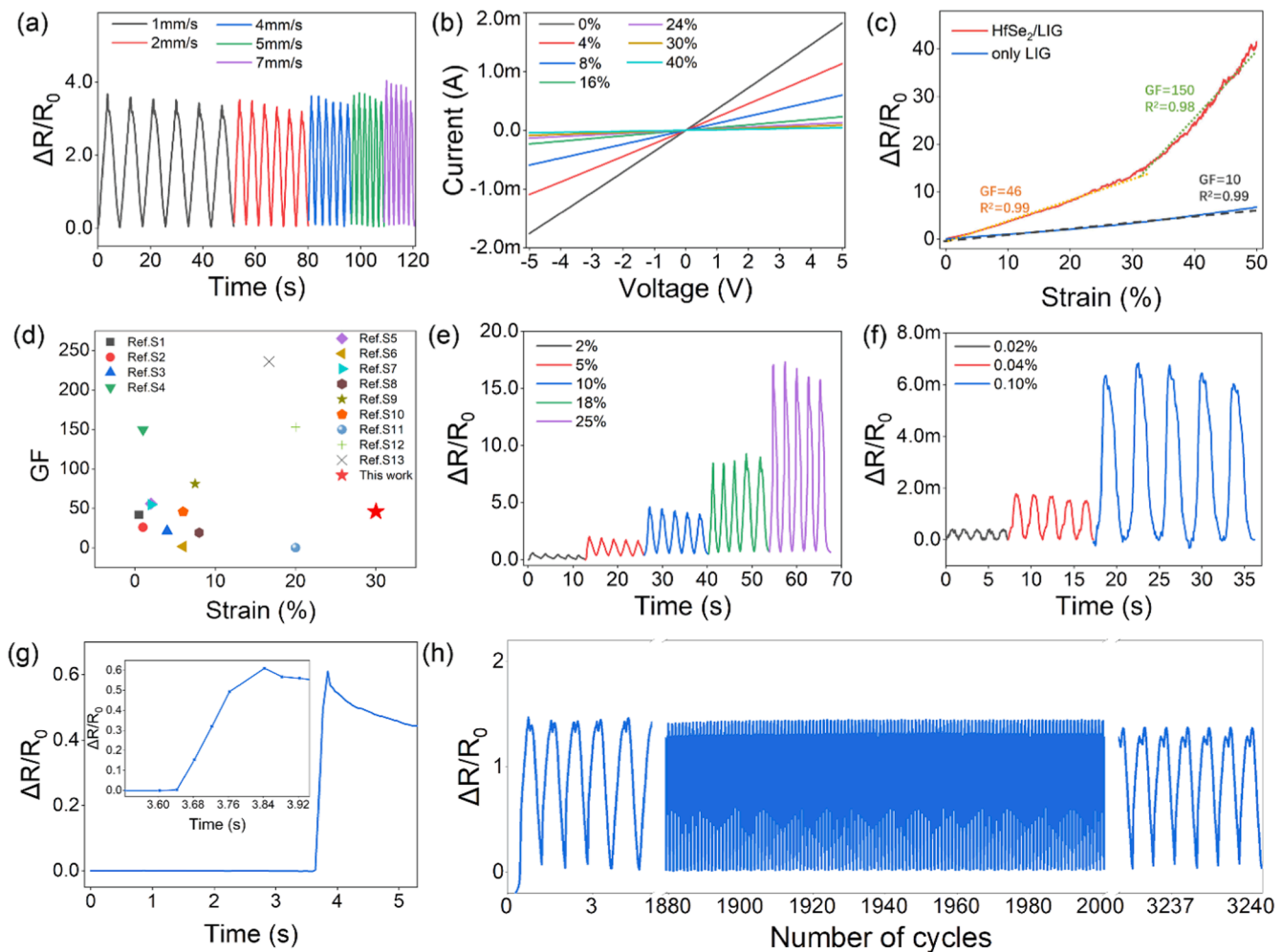
### 3.2. Electromechanical performance of the $\text{HfSe}_2/\text{LIG}$ strain sensor

In this part, the electromechanical performance of  $\text{HfSe}_2/\text{LIG}$  strain sensor need to be tested and evaluated, so the in-situ experimental platform was built and described in detail in the Experimental Section.

As can be seen in Fig. 3a, the electromechanical performance was evaluated initially to see how tensile frequency affected it. The relative resistance change ( $\Delta R/R_0$ ) is nearly the same when stretching 4 mm (10% strain) at various stretching rates (1 mm/s, 2 mm/s, 4 mm/s, 5 mm/s, and 7 mm/s), proving that the device is unaffected by the stretching frequency.

Additionally, the  $\text{HfSe}_2/\text{LIG}$  strain sensor's current-voltage (I-V) properties under various strains were studied. As seen in Fig. 3b, the current follows Ohm's law's linear relationship and rises monotonically as the bias voltage rises. Meanwhile, the slope of the I-V curve flattens out as the strain increases, supporting the piezoresistive characteristics of the  $\text{HfSe}_2/\text{LIG}$  strain sensor.

The GF (gauge factor) was determined using the following calculation to assess the sensitivity of the  $\text{HfSe}_2/\text{LIG}$  strain sensor and compare it to other sensors:



**Fig. 3.** The electromechanical properties of the  $\text{HfSe}_2/\text{LIG}$  strain sensor. (a) Effects of different stretching frequencies on electromechanical responses of  $\text{HfSe}_2/\text{LIG}$  strain sensor. (b) I-V curves of  $\text{HfSe}_2/\text{LIG}$  strain sensor under different tensile strains (0–40%). (c) The comparison of GF between the  $\text{HfSe}_2/\text{LIG}$  strain sensor and LIG-only strain sensor. (d) Comparisons of  $\text{HfSe}_2/\text{LIG}$  strain sensor and recently reported stretchable strain sensors. (e) Time-dependent relative resistance change ( $\Delta R/R_0$ ) of  $\text{HfSe}_2/\text{LIG}$  strain sensor to five continuous stretch/release cycles of 2%, 5%, 10%, 18% and 25% stretch strain. (f) Relative change in resistive response to 0–0.1%–0, 0–0.04%–0, 0–0.02%–0 cyclic strain used to determine the lower detection limit. (g) The response time of the  $\text{HfSe}_2/\text{LIG}$  strain sensor. (h) The electromechanical recyclability of  $\text{HfSe}_2/\text{LIG}$  strain sensor remains stable over 3000 cycles under 4% strain.

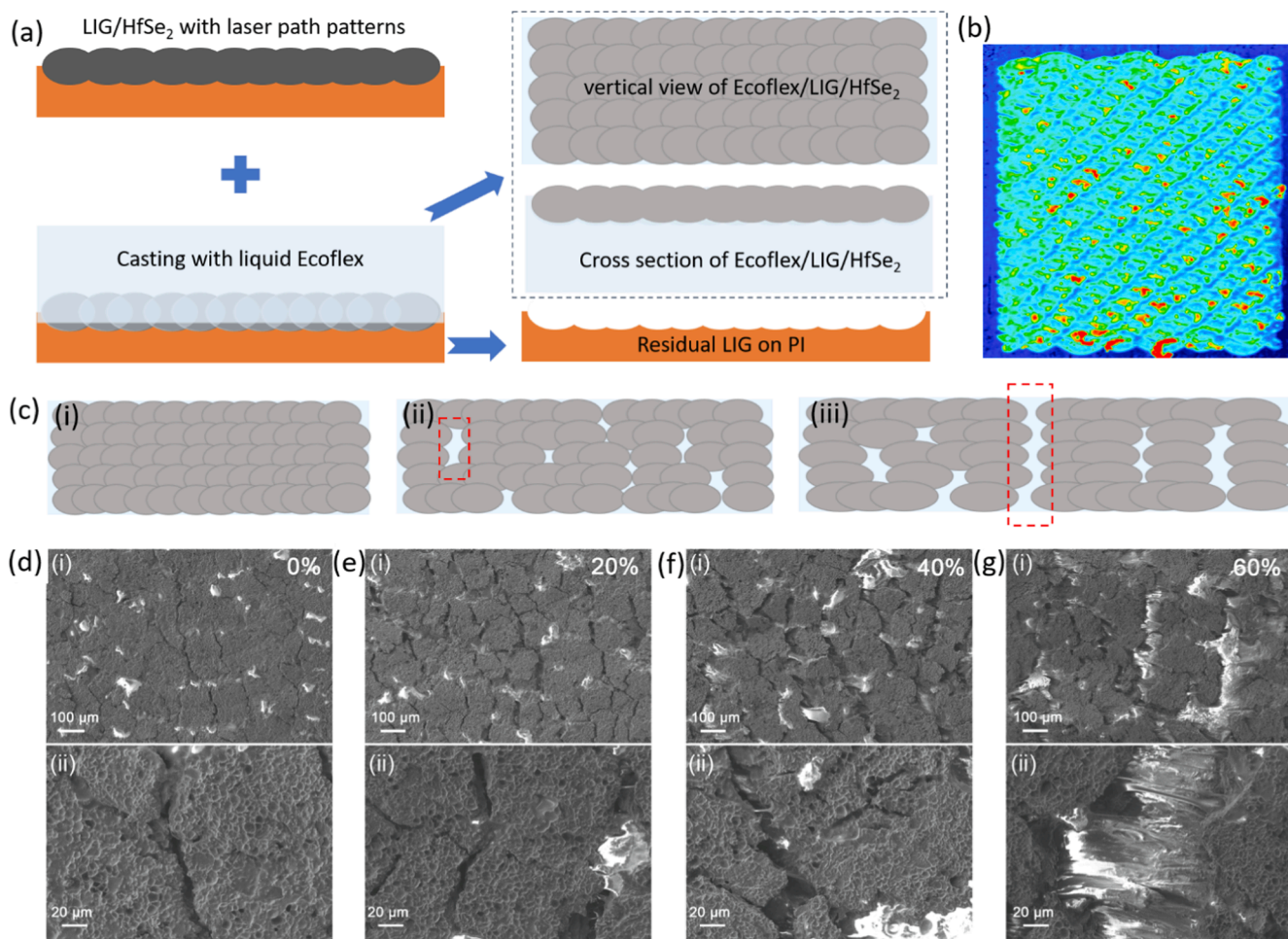
$$GF = \frac{\delta(\Delta R/R_0)}{\delta \varepsilon} = \frac{\delta((R - R_0)/R_0)}{\delta(\Delta L/L_0)} \quad (1)$$

where  $R$  is the resistance at a particular strain and  $R_0$  is the initial resistance. The relative resistance change ( $\Delta R/R_0$ ) of the sensor grows monotonically with the amount of applied tensile strain. Additionally, the slope of the  $\Delta R/R_0$ - $\varepsilon$  curve, which plots the relative resistance change against tensile strain, was used to determine the strain sensitivity of the sensor.

In Fig. 3c, “ $\Delta R/R_0$ - $\varepsilon$ ” curve for the HfSe<sub>2</sub>/LIG strain sensor indicates that it provides a GF of 46 with  $R^2 = 0.99$  up to the strain of 30% and then increases to 150 with  $R^2 = 0.98$  beyond 30%. A sensor made of LIG alone was also fabricated for performance comparison using the same process as the HfSe<sub>2</sub>/LIG sensor. Fig. 3c illustrates that the GF of the HfSe<sub>2</sub>/LIG strain sensor is higher than that of the LIG-only strain sensor. The HfSe<sub>2</sub>/LIG sensor's strain sensing performance (GF of 46 and stretchability of 30%) is also comparable to stretchable strain sensors based on LIG/Pt (GF of 45.6 and stretchability of 6%), [34] graphene/Au (GF of 153 and stretchability of 20%), [35] LIG/MoS<sub>2</sub> (GF of 236.2 and stretchability of 16.7%) [40]. Table S1 compares the detailed strain sensing performance of our strain sensor with the recently reported high-performance strain sensor. Fig. 3d also depicts GFs and the first linear stretching range, illustrating that the HfSe<sub>2</sub>/LIG sensor can provide high sensitivity and good linearity sensing over a broad stretching range.

We have provided a schematic description of the sensing mechanism

based on experimental observations. Fig. 4a shows the surface formation process of the LIG/HfSe<sub>2</sub> sensor. The PI surface forms a characteristic 3D porous structure through laser radiation. Therefore, the liquid Ecoflex can penetrate into the porous structure and fill the micropores after crosslinking during the casting and stripping steps. After the PI is peeled off, LIG/HfSe<sub>2</sub> is brought to the surface. The surface morphology of LIG/HfSe<sub>2</sub> in this work is shown in Fig. 4b, which is determined by the laser scanning interval and laser scanning speed. When the LIG/HfSe<sub>2</sub> encounters external forces, stress concentration occurs in the mechanically weak area, which is the connection between adjacent laser points. Subsequently, many microcracks were generated, which can be further assembled into sensors with strain sensitivity, as shown in Fig. 4c. Fig. 4d-f also shows SEM images of the microstructure of HfSe<sub>2</sub>/LIG composite material at different strain levels, further revealing the strain sensing mechanism of the sensor. The HfSe<sub>2</sub>/LIG surface exhibits obvious cracks in its initial state, as shown in Fig. 4d, which is caused by tearing the HfSe<sub>2</sub>/LIG during peeling off PI. At 20% strain (Fig. 4e), the original crack increases, while the LIG is still in contact; At the same time, new microcracks are generated, so the resistance increases. As the strain increases to 40% (Fig. 4f), the original crack width further increases and the LIG contact begins to weaken. And the new cracks are further increased, which leads to the further increase of the resistance value and the increase of GF. When the strain exceeds 60% (Fig. 4g), the original crack width significantly increases, leading to complete disconnection of LIG and sudden generation of infinite resistance, verifying the macroscopic change in resistance dominated by cracks.



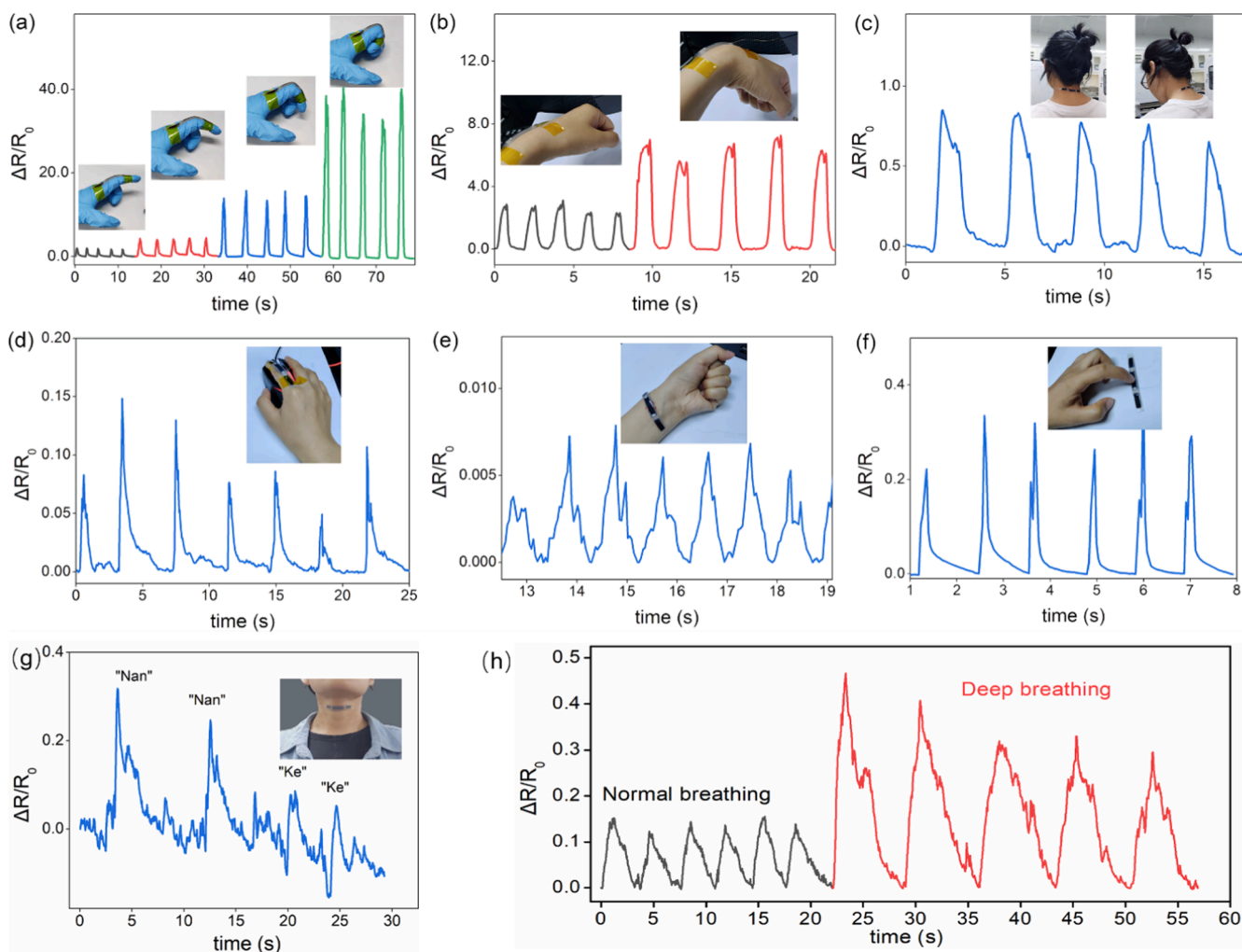
**Fig. 4.** (a) Schematic diagram of the cross-sectional morphology evolution of LIG/HfSe<sub>2</sub> in the casting and peeling process. (b) the 3D morphology map of LIG/HfSe<sub>2</sub> surface. (c) Schematic diagram of cracks in LIG/HfSe<sub>2</sub> sensors under various strains; The complete fracture of the crack occurs beyond the maximum strain (~50%). The SEM images of the HfSe<sub>2</sub>/LIG composite microstructure at various applied strains: (d) 0%, (e) 20%, (f) 40%, and (g) 60%.

Additional studies were carried out to describe the dynamic behavior of the  $\text{HfSe}_2/\text{LIG}$  strain sensor. Fig. 3e shows the sensor's cyclic responses to relatively high strains of 2%, 5%, 10%, 18%, and 25%. The sensor keeps its initial resistance throughout each successive cycle, as seen in Fig. 3e, because the crack re-bridges after the applied strain is withdrawn. The primary cause of the high GF and reversible electrical connection is crack propagation. High sensitivity allowed for the benefit of examining the lower detection limit by continually observing the response while adding small amounts of strain. The sensor can detect a cyclic strain of 0%–0.02%–0%, as illustrated in Fig. 3f, which is close to the best value ever recorded [40,52]. As can be seen in Fig. 3f, the sensor performance was further examined for increasing strain levels of 0.04% (red line) and 0.1% (blue line). The findings demonstrate that under each strain condition, the relative change in resistance response is very good and fully recovers following release. Additionally, strains ranging from 4% to 20% were applied to the sensor to evaluate its dynamic response. The sensor was stretched and held for 5 s, then released and held for an additional 5 s as the resistance was recorded continuously, as seen in Fig. S3a. During applied strain, the sensor's response remains constant and returns to its eigenvalues upon release. Similarly, the sensor's staircase response was examined by sequentially stretching it by 4% strain and holding it for 5 s, as seen in Fig. S3b. And when it reached 28%, the strain was released in the same step size as stretching. The reactions to the stretching and releasing curves are symmetrical, but

when releasing, there is an overshoot signal caused by the viscoelasticity of the flexible substrate [4]. Fig. 3g depicts dynamic response time of the sensor. The dynamic response time is determined by how fast the sensor reacts to strain loading. When the stretching speed was 7 mm/s (the maximum allowable stretching speed in this work), the time interval between adjacent horizontal shifts was observed as 0.20 s, indicating that the response after stretching is fast.

Furthermore, to assess the sensor's long-term durability, more than 3000 strain/release cycles (4% strain) were applied to test the electromechanical stability. The sensor responses did not differ significantly during the recycles test, as shown in Fig. 3h. After 3000 recycles, the device still performs well, effectively retaining its electromechanical properties. We discovered that even after 3000 electromechanical test cycles, the value of  $\Delta R/R_0$  decreased from 1.44 to 1.36, indicating the sensor's long-term durability. To further verify the repeatability of the strain sensor, the surface morphology of the device was characterized by SEM after stretching for different cycles, with a stretching frequency of 1 Hz and a strain of 40%. From the SEM images of Figure S4, it can be seen that there is no significant difference in the surface crack morphology after 100, 500, 1000, and 2000 cycles of stretching, further demonstrating the stability and reliability of the device during repeated stretching. The excellent endurance of sensor is attributable to the capacity of crack repair during strain release to be reversed.

In addition to stretching, the sensing performance during pressing



**Fig. 5.** The application of the  $\text{HfSe}_2/\text{LIG}$  device for various real-time signals. (a) Detect human motion by installing strain sensors on the finger joints. Relative changes in the resistive response of continuous bending/relaxation under different bending angles (30°, 60°, 90°, and 120°). (b) Relative resistance changes of the sensor when monitoring wrist bending. Relative resistance changes of the sensor when (c) the sensor is attached to the cervical spine, (d) the mouse is clicked, (e) testing wrist pulse, (f) pressing the sensor. (g) Relative resistance change of the sensor when the wearer spoke "Nan", "Ke". (h) Breathing test.

was also investigated. Fig. S3c depicts the device's response to pressure, and the value of  $\Delta R/R_0$  increases as pressure increases, indicating that the  $\text{HfSe}_2/\text{LIG}$  sensor has attractive pressure monitoring capability.

### 3.3. Applications of the $\text{HfSe}_2/\text{LIG}$ strain sensor

To demonstrate that the  $\text{HfSe}_2/\text{LIG}$  strain sensor, as a motion detector of an integrated health monitoring platform, can perceive a large number of joint-level and delicate skin-level strain signals, we place the sensors in various positions on the human body and track their reactions in real time.

For deformation caused by violent human motion, the sensor is fixed on the wrist and index finger joint by tightly wrapping bandages. The relative resistance response to various degrees of finger bending is shown in Fig. 5a. The sensor's resistance rises by approximately 180%, 410%, 1300%, and 3400% when the finger is bent by 30°, 60°, 90°, and 120°, respectively. When the sensor is mounted to the back of a person's wrist, as in Fig. 5b, it then exhibits a very steady resistance change to wrist bending. The above results show that  $\text{HfSe}_2/\text{LIG}$  strain sensor has great strain sensing ability and can be embedded in smart wearable devices for tracking human motion. Fig. 5c shows a highly reproducible and reversible resistance signal as it captures the sensor's resistance change in response to the volunteer bowing or raising her head, which indicates that it has great prospect in helping patients with cervical spondylosis rehabilitate. The test when a finger clicks the mouse is shown schematically in Fig. 5d, along with the associated  $\Delta R/R_0$ -time curve. At the top of this curve, the mouse is clicked by the finger, and at the bottom, the released state is represented. When the finger clicks the mouse, the skin of the finger is slightly deformed, and the sensor can sensitively detect this change.

For correct medical diagnosis, it is also crucial to accurately track respiration and blood circulation, therefore it is also required to keep an eye on minute physiological signs like wrist pulse. Similarly, it has been demonstrated that the  $\text{HfSe}_2/\text{LIG}$  sensor is sensitive enough to detect wrist pulsation. The result is shown in Fig. 5e. The graphic shows three distinctive peaks: the percussion peak (P), tidal peak (T), and diastolic peak (D). Other detection of subtle motion has also been tested. As expected, when the wearer utters different words such as "Nan" and "Ke", the  $\text{HfSe}_2/\text{LIG}$  strain sensor is connected to the throat to detect the vibration signal of the vocal cords (Fig. 5g). In addition, the sensor can also be used to monitor respiratory rate. As shown in Fig. 5h, different respiratory states can be distinguished by the amplitude, and frequency of the sensing signal, indicating the potential application of detecting subtle motion.

Furthermore, Fig. 5f shows the schematic diagram of the pressure test when finger pressing, and the corresponding  $\Delta R/R_0$ -time curve. The top of this curve is finger pressed, while the bottom stands for the released state, which shows that the sensor also has sufficient sensitivity to detect pressure.

## 4. Conclusion

In conclusion,  $\text{HfSe}_2/\text{LIG}$  composites were prepared in this work using a straightforward procedure. Three-dimensional porous graphene modified by  $\text{HfSe}_2$  was synthesized by irradiating multilayer  $\text{HfSe}_2$  coated on commercial PI films with  $\text{CO}_2$  infrared laser. After being transferred to the flexible substrate of Ecoflex, it had high stretchability, hydrophobicity and robustness, and obtained excellent electromechanical properties. So, the electromechanical characteristics of  $\text{HfSe}_2/\text{LIG}$  strain sensor were examined. The  $\text{HfSe}_2/\text{LIG}$  strain sensor provides a GF of 46 with good linearity ( $R^2 = 0.99$ ) in a broad tensile range (0–30%) and then increases to 150 with  $R^2 = 0.98$  beyond 30%. The  $\text{HfSe}_2/\text{LIG}$  strain sensor demonstrated excellent sensitivity ( $\text{GF}_{\text{max}} \approx 150$ ), low detection limit of 0.02% and great tensile durability (>3000 cycles). Its potential use as a wearable strain sensor is assessed in light of its exceptional sensing capabilities. The sensor can reliably pick up signals

of minute artery activity as well as a variety of joint motions (including those of the fingers, wrists, and neck). The sensor based on  $\text{HfSe}_2/\text{LIG}$  has potential uses in wearable intelligent electronic devices, healthcare applications, and tracking human movements.

### CRediT authorship contribution statement

**Huiru Yang:** Conceptualization, Investigation, Writing – original draft. **Shaogang Wang:** Methodology, Resources. **Qianming Huang:** Methodology, Visualization. **Chunjian Tan:** Formal analysis, Investigation. **Chenshan Gao:** Data curation, Visualization. **Siyuan Xu:** Investigation. **Huaiyu Ye:** Supervision, Funding acquisition, Writing – review & editing, Validation. **Guoqi Zhang:** Funding acquisition.

### Declaration of Competing Interest

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

### Data availability

Data will be made available on request.

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### Appendix A. Supplementary material

Supplementary data to this article can be found online at <https://doi.org/10.1016/j.apsusc.2023.157772>.

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